

**PATENT APPLICATION****Docket No. 9898-321****Client No. SS-18146-US**

Applicant: Ki-Yeon Park, Sung-Tae Kim, Young-Sun Kim, In-Sung Park, Jae-Hyun Yeo and Ki-Vin Im

Serial No. not yet assigned Examiner: not yet assigned

Filing Date: November 12, 2003 Art Unit: not yet assigned

Title: CAPACITOR OF SEMICONDUCTOR MEMORY DEVICE THAT HAS COMPOSITE  
Al<sub>2</sub>O<sub>3</sub>/HfO<sub>2</sub> DIELECTRIC LAYER AND METHOD OF MANUFACTURING THE SAME**INFORMATION DISCLOSURE CITATION  
FORM PTO-1449 (Modified)****U.S. PATENT DOCUMENTS**

| <u>Exam</u><br><u>Init</u> | <u>Ref</u> | <u>Document</u><br><u>Number</u> | <u>Publication</u><br><u>Date</u> | <u>Name</u>         | <u>Class</u> | <u>Sub</u><br><u>Class</u> |
|----------------------------|------------|----------------------------------|-----------------------------------|---------------------|--------------|----------------------------|
| _____                      | _____      | 2001-0024387A1                   | 9/21/2001                         | Raaijmakers, et al. |              |                            |

**FOREIGN PATENT DOCUMENTS**

| <u>Exam</u><br><u>Init</u> | <u>Ref</u> | <u>Document</u><br><u>Number</u> | <u>Publication</u><br><u>Date</u> | <u>Country</u> | <u>Name</u> |
|----------------------------|------------|----------------------------------|-----------------------------------|----------------|-------------|
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**OTHER DOCUMENTS**

| <u>Exam</u><br><u>Init</u> | <u>Ref</u> | <u>Author, Title, Date, Pertinent Pages, Etc.)</u> |
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Examiner: \_\_\_\_\_

Date Considered: \_\_\_\_\_